A Product Line of Diodes Incorporated

## Features

- $\mathrm{BV}_{\text {CEO }}>60 \mathrm{~V}$
- $\quad I_{C}=2 \mathrm{~A}$ High Continuous Collector Current
- $\mathrm{I}_{\mathrm{CM}}=6 \mathrm{~A}$ Peak Pulse Current
- $\mathrm{T}_{\mathrm{J}}$ up to $+200^{\circ} \mathrm{C}$ for High Temperature Operation
- Low Saturation Voltage $<300 \mathrm{mV}$ @ 1 A
- $P_{D}=1 W$ Power dissipation
- Totally Lead-Free \& Fully RoHS compliant (Notes 1 \& 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)


## Mechanical Data

- Case: E-Line (TO-92 Compatible)
- Case Material: molded plastic, "G reen" Molding Compound
- UL Flammability Classification Rating 94V-0
- Terminals: Finish - Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 © ${ }^{\text {e }}$
- Weight: 0.159 grams (approximate)


Ordering Information (Notes $4 \& 5$ )

| Part Number | Compliance | Marking | Case | Leads | Quantity |
| :---: | :---: | :---: | :---: | :---: | :---: |
| ZTX651 | AEC-Q101 | ZTX651 | E-Line | Straight | 4,000 loose in a Box |
| ZTX651Q | Automotive | ZTX651 | E-Line | Straight | 4,000 loose in a Box |
| ZTX651STZ | AEC-Q101 | ZTX651 | E-Line | J oggled | 2,000 taped per Ammo Box |
| ZTX651QSTZ | Automotive | ZTX651 | E-Line | J oggled | 2,000 taped per Ammo Box |

Notes: $\quad 1$. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) \& 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain $<900 \mathrm{ppm}$ bromine, $<900 \mathrm{ppm}$ chlorine ( $<1500 \mathrm{ppm}$ total $\mathrm{Br}+\mathrm{CI}$ ) and $<1000 \mathrm{ppm}$ antimony compounds.
4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product compliance definitions/.
5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## Marking Information



Rounded Face View

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ZTX651

Maximum Ratings ( $@ T_{A}=+25^{\circ} \mathrm{C}$, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
| :--- | :---: | :---: | :---: |
| Collector-Base Voltage | V $_{\text {CBO }}$ | 80 | V |
| Collector-E mitter Voltage | $\mathrm{V}_{\text {CEO }}$ | 60 | V |
| Emitter-Base Voltage | $\mathrm{V}_{\text {EBO }}$ | 7 | V |
| Continuous Collector Current | $\mathrm{IC}_{C}$ | 2 | A |
| Peak Pulse Current | $\mathrm{I}_{\text {CM }}$ | 6 | A |

Thermal Characteristics ( $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
| :---: | :---: | :---: | :---: |
| Power Dissipation (Note 6) | $\mathrm{P}_{\mathrm{D}}$ | 1.5 | W |
| Power Dissipation (Note 7) | PD | 1 | W |
| Thermal Resistance J unction to Ambient (Note 6) | R өj A | 116 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Thermal Resistance J unction to Ambient (Note 7) | $\mathrm{R}_{\text {® }} \mathrm{A}$ | 175 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Thermal Resistance J unction to Lead (Note 8) | R өj L | 70 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Operating and Storage Temperature Range | TJ, $\mathrm{T}_{\text {stg }}$ | -55 to +200 | ${ }^{\circ} \mathrm{C}$ |

## ESD Ratings (Note 9)

| Characteristic | Symbol | Value | Unit | JEDEC Class |
| :--- | :---: | :---: | :---: | :---: |
| Electrostatic Discharge - Human Body Model | ESD HBM | $\geq 4,000$ | V | 3A |
| Electrostatic Discharge - Machine Model | ESD MM | $\geq 400$ | V | C |

Notes: $\quad 6$. For a through-hole device mounted at the seating plane ( 2.5 mm lead length) with the collector lead on $25 \mathrm{~mm} \times 25 \mathrm{~mm} 10 \mathrm{copper}$ that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
7. Same as note (5), except the device is mounted on minimum recommended pad layout with 12 mm lead length from the bottom of package to the board.
8. Thermal resistance from junction to solder-point at the seating plane ( 2.5 mm from the bottom of package along the collector lead).
9. Refer to JEDEC specification J ESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information



Derating curve


Maximum transient thermal impedance

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ZTX651

Electrical Characteristics ( $@ \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$, unless otherwise specified.)

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Collector-Base Breakdown Voltage | BV CBO | 80 | - | - | V | $\mathrm{IC}=100 \mu \mathrm{~A}$ |
| Collector-Emitter Breakdown Voltage (Note 10) | BV CEO | 60 | - | - | V | $\mathrm{IC}_{\mathrm{C}}=10 \mathrm{~mA}$ |
| Emitter-Base Breakdown Voltage | BVEbo | 7 | - | - | V | $\mathrm{IE}_{\mathrm{E}}=100 \mu \mathrm{~A}$ |
| Collector Cut-off Current | Icbo | - | - | $\begin{aligned} & 0.1 \\ & 10 \\ & \hline \end{aligned}$ | $\underset{\mu \mathrm{A}}{\mu \mathrm{~A}}$ | $\begin{aligned} & \mathrm{V}_{C B}=60 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CB}}=60 \mathrm{~V}, \mathrm{~T}_{\mathrm{amb}}=100^{\circ} \mathrm{C} \end{aligned}$ |
| Emitter Cut-off Current | Iebo | - | - | 0.1 | $\mu \mathrm{A}$ | $\mathrm{V}_{\text {EB }}=6 \mathrm{~V}$ |
| Collector-Emitter Saturation Voltage (Note 10) | $V_{\text {CE (sat) }}$ | - | $\begin{aligned} & 120 \\ & 230 \end{aligned}$ | $\begin{aligned} & 300 \\ & 500 \end{aligned}$ | mV | $\begin{aligned} & \mathrm{I}_{\mathrm{C}}=1 \mathrm{~A}, \mathrm{I}_{\mathrm{B}}=100 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{C}}=2 \mathrm{~A}, \mathrm{I}_{\mathrm{B}}=200 \mathrm{~mA} \end{aligned}$ |
| Base-E mitter Saturation Voltage (Note 10) | $\mathrm{V}_{\mathrm{BE} \text { (sat) }}$ | - | 0.9 | 1.25 | V | $\mathrm{IC}_{\mathrm{C}}=1 \mathrm{~A}, \mathrm{I}_{\mathrm{B}}=100 \mathrm{~mA}$ |
| Base-Emitter Turn-On Voltage (Note 10) | $\mathrm{V}_{\mathrm{BE} \text { (on) }}$ | - | 0.8 | 1 | V | $\mathrm{I}_{\mathrm{C}}=1 \mathrm{~A}, \mathrm{~V}_{\text {CE }}=2 \mathrm{~V}$ |
| DC Current Gain (Note 10) | $\mathrm{hfe}_{\text {F }}$ | $\begin{gathered} 70 \\ 100 \\ 80 \\ 40 \end{gathered}$ | $\begin{gathered} 200 \\ 200 \\ 170 \\ 80 \end{gathered}$ | $\begin{gathered} \overline{-} 00 \\ - \end{gathered}$ | - | $\begin{aligned} & \mathrm{I}_{\mathrm{C}}=50 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=2 \mathrm{~V} \\ & \mathrm{IC}=500 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=2 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{C}} \mathrm{C}=1 \mathrm{~A}, \mathrm{~V}_{\mathrm{CE}}=2 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{C}}=2 \mathrm{~A}, \mathrm{~V}_{\mathrm{CE}}=2 \mathrm{~V} \\ & \hline \end{aligned}$ |
| Current Gain-Bandwidth Product (Note 10) | $\mathrm{f}_{\mathrm{T}}$ | 140 | 175 | - | MHz | $\begin{aligned} & \mathrm{V}_{\mathrm{CE}}=5 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=100 \mathrm{~mA} \\ & \mathrm{f}=100 \mathrm{MHz} \end{aligned}$ |
| Output Capacitance (Note 10) | Cobo | - | - | 30 | pF | $\mathrm{V}_{C B}=10 \mathrm{~V} . \mathrm{f}=1 \mathrm{MHz}$ |
| Turn-On Times | ton | - | 45 | - | ns | $\mathrm{IC}_{\mathrm{C}}=500 \mathrm{~mA}, \mathrm{I}_{\mathrm{B} 1}=\mathrm{I}_{\mathrm{B} 2}=50 \mathrm{~mA}$, |
| Turn-Off Times | toff | - | 800 | - | ns | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}$ |

[^0]ZTX651

Typical Electrical Characteristics $\left(@ T_{A}=+25^{\circ} \mathrm{C}\right.$, unless otherwise specified.)


hFE v IC




## Package Outline Dimensions

Please see AP 02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

$b 1 \underbrace{\phi-\phi-\phi}$ R $1.14(.045)$


| E-Line |  |  |  |
| :---: | :---: | :---: | :---: |
| Dim | Min | Max | Typ |
| A | 2.16 | 2.41 | - |
| b | 0.41 | 0.495 | - |
| b1 | 0.41 | 0.495 | - |
| D | 4.37 | 4.77 | - |
| E | 3.61 | 4.01 | - |
| e | - | - | 1.27 |
| e2 | - | - | 2.54 |
| F | - | 2.50 | - |
| L | 13.00 | 13.97 | - |
| L1 | 2.50 | 3.50 | - |
| All Dimensions in mm |  |  |  |

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[^0]:    Notes: $\quad 10$. Measured under pulsed conditions. Pulse width $\leq 300 \mu \mathrm{~s}$. Duty cycle $\leq 2 \%$

